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Description

This invention relates to electrical power transmission systems and more particularly, but not exclusively, to high voltage electrical power cables, used in power transmission and distribution lines, for example, and is concerned particularly with such cables that are designed to attenuate voltage surges, caused by lightning and by switching for example, consisting largely of high frequency components.

In particular, this invention relates to an electrical power transmission system (or shielded power cable) of the type comprising inner and outer coaxial conductors separated by an insulation system, the insulation system extending longitudinally with respect to the conductors and comprising first, second and optionally third coaxial layers defining a displacement current path between the conductors for high frequency currents, the first layer being a semiconductive layer presenting a conductance G_1 and a capacitance C_1 per unit length, and the second layer being an insulating layer around the first layer and presenting a capacitance C per unit length, and the optional third layer being disposed between the second layer and outer conductor and in the displacement current path between the conductors, and being a semiconductive layer presenting a conductance G_2 and a capacitance C_2 per unit length.

Cables of this type are known (as explained, for example, in patent specification US-A-3643004), and typically the semconductive layer(s) consist of a conductive polymer or an insulator such as polyolefin filled with a conducting matrix.

All cables presently manufactured will attenuate surges 10 some extent, and shielded power cables of the type referred to above will certainly do so. However, present manufacturing methods do not take advantage of the possibility of optimizing surge attenuation owing to their reliance on materials which preclude the possibility.

The present invention is based on the discovery that the configuration and the materials of the layers forming the cable can be optimized so as to maximize the power loss per unit length of cable at a given high frequency, or at a given range of frequencies, and so to maximize the power loss per unit length for a typical surge. Thus it becomes possible to design a cable so as to minimise the propagation of surges along that line. The ability of the cable to transmit power frequency (e.g. 60 Hz) currents is no way impaired.

If the inner semiconductive layer presents a conductance G_1 and a capacitance C_1 per unit length of cable, if the outer semiconductive layer presents a conductance G_2 and a capacitance C_2 per unit length of cable, and if the intermediate layer with negligible conductance presents a capacitance C per unit length of cable, then the power loss P per unit length of cable with one volt applied at a given frequency $w/2\pi$ is given by

$$P = G_1 \mid V_1 \mid^2 + G_2 \mid V_2 \mid^2$$

V_1 and V_2 being the voltage drops across the inner semiconductive layer and the outer semiconductive layer, respectively,

where

$$V_1 = Z_1/(Z_1 + Z_2 + Z_3 + Z)$$

and

$$V_2 = Z_2/(Z_1 + Z_2 + Z_3 + Z)$$

where

$$Z_1 = \frac{1.}{G_1} \frac{1-jwC_1}{1+(wC_1/G_1)^2}$$

$$Z_2 = \frac{1.}{G_2} \frac{1-jwC_2}{1+(wC_2/G_2)^2}$$

Z_3 = -j/wc,

and

$$Z = \{\sqrt{w\mu_o}\left(\frac{1}{2\pi a_1\sqrt{2\sigma_1}} + \frac{1}{2\pi a_2\sqrt{2\sigma_3}}\right)(1+j)\} + \frac{jw\mu_o \ln(a_2/a_1)}{2\pi}$$

where
μ = $400\pi \times 10^{-9}$
a_1 = radius of inner conductor
a_2 = inner radius of outer conductor
σ_1 = conductivity of inner conductor
σ_3 = conductivity of outer conductor
The parameters C_1, C_2, G_1 and G_2 can be expressed as follows:

$$C_1 = \frac{2\pi\epsilon_r\epsilon_0}{\log \dfrac{a_1 + t_1}{a_1}}$$

$$C_2 = \frac{2\pi\epsilon_r\epsilon_0}{\log \dfrac{a_2}{a_2 - t_2}}$$

$$G_1 = \frac{2\pi\sigma_4}{\log \dfrac{a_1 + t_1}{a_1}}$$

$$G_2 = \frac{2\pi\sigma_4}{\log \dfrac{a_2}{a_2 - t_2}}$$

where
ϵ_0 = 8.85×10^{-12}
ϵ_r = relative permittivity of the semiconductive layers
σ_2 = conductivity of the inner semiconductive layer
σ_4 = conductivity of the outer semiconductive layer
t_1 = thickness of the inner semiconductive layer
t_2 = thickness of the outer semiconductive layer.

In order to maximise the power loss per unit length P, at the selected frequency $w/2\pi$, it is necessary that the relative permittivity of the semiconductive layers be small and that the conductivities of the inner and outer conductors, and the dielectric constants of the inner and outer semiconductor layers be such that the following equations are satisfied:

$$\frac{\partial P}{\partial G_1} = 0 \quad \text{and} \quad \frac{\partial P}{\partial G_2} = 0$$

In other words, the power loss per unit length of cable must be maximised with respect to the conductance of each of the semiconductive layers.

Accordingly, the system or cable of the present invention is characterised in that the conductivity, relative permittivity and the thickness of the first layer (and optionally also the third layer) are such that the power loss per unit length in the first layer (and optionally also in the third layer) due to displacement current flowing radially through the first, second (and optionally third) layers between the inner and outer conductors is maximized with respect to the conductance G_1 per unit length of the first layer (and optionally with respect to the conductance G_2 per unit length of the third layer), at least over the frequency range 0.1 MHz - 50 MHz.

As mentioned above, the material most commonly used for the semiconductive layer(s) of the cable insulation is a polyolefin loaded with carbon black which, owing to the highly structured nature of carbon black, has a high permittivity and exhibits sharp changes in both permittivity and conductivity with frequency. The inventors have reasoned that, to be useful for surge attenuation, the material should offer low permittivity and exhibit no sharp changes in permittivity and conductivity with increasing frequency since this will decrease the surge attenuation. The inventors have investigated the electrical properties of a range of materials which might be used in cable manufacture and have selected those materials which exhibit desirable electrical properties consistent with ease and economy of manufacture.

Each semiconductive layer may be an extrudable polymeric material, such as a polyolefin or a blend of rubbers, loaded with a low structure particulate conductive filler. The conductive filler may consist of carbon fibres, or carbon spheres, or be metallic. (It may be noted that the use of a metallic filler in a plastic base material in the construction of a radio frequency interference suppressor cable is mentioned in patent specification US-A-4301428.)

Lastly, it should be noted that patent specification GB-A-1134636 describes a cable conductor coated with a semiconductor layer, in which the propagation speed is increased so as to reduce raidiation from the cable, and in which high frequency currents tend to localise. The layer is dissipative so as to absorb the high frequency electrical energy.

In order that the invention may be readily understood, the design and construction of a surge attenuating cable in accordance with the invention will now be described, by way of example, with reference to the accompanying drawings. In the drawings:

Figure 1 is a diagram of one segment of the equivalent circuit of a conventional power cable transmission line;

Figure 2 is a diagrammatic cross-sectional view of a shielded power cable in accordance with the invention;

Figure 3 shows one segment of the equivalent circuit of the cable illustrated in Figure 2;

Figure 4 is a graph illustrating relative power loss in a cable as a function of capacitance of the semiconductive layers;

Figure 5 is a graph illustrating relative power loss in a cable as a function of conductance of the semiconductive layers;

Figure 6 illustrates the input/output voltage relationship for a lightning surge at the beginning and end of a 1-km optimized power cable; and

Figure 7 illustrates the change in a fast wavefront switching surge as it propagates through 100 m. of an optimized power cable.

From theoretical considerations the inventors have correctly predicted the propagation characteristics of high frequency signals in high voltage power cables of the type having semiconductive shields. It was predicted, and subsequently confirmed experimentally, that for frequencies in excess in 1 MHz the major power loss in such a cable occurs in the semiconductive shields. It follows that the attenuation of high frequency signals propagated along such cables is primarily determined by the electrical and geometrical characteristics of the semiconductive shields.

Power transmission and distribution of lines having significant high frequency attenuation may be useful in several power system applications. Since lightning and switching surges consist largely of high-frequency components, surges introduced into such a cable are rapidly attenuated as they propagate. The magnitude of the voltage at the far end of the cable will be reduced and the rise time of the surge will be increased, exposing terminal quipment such as transformers and rotating machines to a reduced hazard level. In

addition, less of the power line itself is exposed to the initial high-voltage surge, thereby reducing the probability of line or cable failure.

The implications of these considerations will now be examined with reference to particular applications, including shielded high voltage power cables used in distribution and generator station service situations, and gas-insulated bus ducts.

One segment of the equivalent circuit of a conventional transmission line is shown in Figure 1. The propagation characteristics of signals can be estimated from the per unit length cable characteristics. In particular, the attenuation is determined from the real part of $\sqrt{ZY}$. If no semiconductive shields are present, the attenuation is dominated by the skin effect of the conductor as well as losses in the dielectric. However, it is known that the measured attenuation of high-frequency signals in high voltage power cables has always been much greater than estimated by the simple transmission line model of Figure 1. A new model has therefore been developed by the inventors, which takes into account the inner and outer semiconductive (e.g., carbon-loaded) shields that are a part of all shielded power cables. In this model, the capacitive charging, or displacement, current must pass radially through the semiconductive shields, creating a power loss in the shields and thus increasing the cable's attenuation.

As illustrated in Figure 2, a shielded power cable typically comprises a central conductor 10, which is usually stranded, an outer conductor 11, which is also stranded, or alternatively fabricated from metallic tapes, and a cable insulation system consisting essentially of three coaxial layers, namely an inner semiconductive layer 12, an outer semiconductive layer 13, and an intermediate non-conductive layer 14. The intermediate layer is of a polymeric dielectric material, such as a polyolefin or blend of rubbers, commonly used in cable manufacture. The layers 12 and 13 are also of such material and are made semiconductive by the incorporation of conductive fillers, such as carbon black, graphite etc.

Figure 3 shows the lumped element equivalent circuit of such a cable, or rather one segment of the circuit representing an elemental length. In this diagram the inner semiconductive layer 12 is represented by a capacitance C_1 shunted by a conductance G_1; the outer semiconductive layer 13 is represented by a capacitance C_2 shunted by a conductance G_2; and the intermediate layer 14 is represented by a capacitance C, its conductance being negligible. The conductor is represented by the resistive-inductive impedance element Z. Since the insulation displacement current increases with frequency, the attenuation of the cable must also increase with frequency. The influence of the semiconductive shields on power loss at power frequency (typically 60 Hz) is negligible.

Although the attenuation in a standard power cable is greater than predicted by the conventional transmission line model, it is not as high as it could be. That is, by adjusting the capacitance and conductance of the semiconductive layers, much greater attenuation is possible. As stated above, this greater attenuation may reduce the risk of failure of the cable and connected equipment.

Graphs of real power loss, which is directly proportional to surge attenuation, against semiconductive layer capacitance and conductance are shown in Figures 4 and 5. These plots are for a single semiconductive layer 3 mm. thick on the surface of the high voltage conductor in a simple cable. It is apparent from Figure 4 that increasing the capacitance of the semiconductive layer, by decreasing the layer thickness or its dielectric permittivity, decreases the power loss, and so decreases the attenuation. In order to maximize the attenuation, therefore, the capacitance of the layer should be as low as possible. However, the minimum capacitance attainable is limited by the geometry of the cable and by the electrical properties of the materials used. Referring now to Figure 5, which is a plot of power loss as a function of conductance of the semiconductive layer, it will be seen that there is an optimum conductance which will maximize the power loss and therefore the attenuation. Analysis of the more typical power cable design with two semiconductive layers reveals the same criteria.

SF_6 Switchgear

Another possible application is to cover the high voltage conductor in a gas-insulated switchgear with an optimized semiconductive layer. High-voltage transients with frequencies up to 50 MHz are generated by disconnect-switch operations. These transients are suspected of causing breakdowns in the gas-insulated switchgear. Table 1 shows the maximum possible attenuation obtainable in a 230-kV bus duct with a 3-mm. thick semiconductive layer over the conductor.

TABLE I

MAXIMUM POSSIBLE ATTENUATIONS

Application	Insulation Capacitance (pF/m)	Semicon Capacitance (pF/m)		Semicon Conductance (S/m)		Attenuation (db/m)		
		Inner	Outer	Inner	Outer	1 MHz	10 MHz	50 MHz
Optimized SF_6 Bus Duct (230 kV, 0.11 m dia conductor)	57	4700*	-	0.28	-	2×10^{-4}	0.006	0.01
Commercial Power Cable (46 kV, EPR, 2/0(34mm²))	192	3600	10,000	0.4	0.9	<0.01	0.045	0.2
Optimized Power Cable (46 kV, EPR, 2/0(34mm²))	192	185**	400	0.004	0.08	0.02	0.15	3.4
Optimized Power Cable 15 kV, XLPE, 125 mm² (250 MCM))	365	165**	303	0.06	0.1	<0.1	0.35	5.0

* minimum capacitance, 3 mm thick, $\varepsilon_r = 2.3$

** minimum capacitance, 3 mm thick, $\varepsilon_r = 1.0$

Shielded Power Cable

Shielded power cables already contain inner and outer semiconductive layers arranged coaxially as shown in Figure 2. However, the attenuation of commercially available power cables is quite low when

compared to a cable made with "optimized" semiconductive layers. Table 1 gives attenuations for 46-kV EPR-insulated cable with and without optimized semiconductive layers. The attenuations in the commercial cable were measured, whereas the values quoted for the optimized cable are calculated.

The attenuations possible in shielded power cables are reasonably high. In an underground distribution system, a cable may be exposed to lightning surges (frequencies of several hundred kHz) whereas in generator station service use, fast switching surges can be present (frequencies up to 20 MHz). The effect of the optimized cable on such transients can be estimated using Fourier transforms.

Propagation of surges in optimized power cable

The output voltage from a 1 km. optimized 46-kV EPR Cable (Table 1) when exposed to an input 1-μs rise time lightning surge is shown in Figure 6. The wavefront is slowed to about 5μs (10%-90%) with the magnitude reduced from 1 pμ to 0.9 pμ. By comparison, the output of 1 km of the commercial (non-optimized) 46-kV cable is virtually unchanged. The drop in lightning impulse amplitude is probably not enough to have an important effect on the distribution cable system reliability, except for very long runs, greater than 5 km. The effect of the optimized cable on distribution transformer reliability may be beneficial however, since the wavefront is considerably slowed. Fast wavefronts can cause the surge voltage to "pile-up" across the first few turns of a transformer winding, resulting in failure of turn insulation.

Surges with rise times of 0.1 to 0.2 μs can result from switch and circuit breaker operations. These surges, when applied to rotating machines such as hydraulic generators and large motors, are known to cause catastrophic insulation failure of the turns. The primary means to mitigate the effect of these surges is to increase the rise time by means of "wave-sloping" capacitors mounted at the terminals. These capacitors, however, may not be effective if they are not well grounded with low-inductance leads, and the capacitors themselves can become faulted. If surge attenuating cables are used between the switches and the rotating machines, the fast risetime will be slowed sufficiently without any increased cost or reduced reliability.

Figure 5 shows the effect on a 0.1-μs rise time transient propagating through only 100 m of the optimized 46-kV cable. The wavefront is stretched to 0.5 μs (10%-90%), and the output magnitude is 93% of the input. After 1 km, the wavefront is 1.8 μs long, and the amplitude is 0.72 pμ. For the 15-kV cable in Table 1, which is more typical of a generator station service cable, the rise time would be even longer because of the greater attenuation. The optimized power cable is therefore of use in reducing the surge hazard in generator station service applications.

The problem of designing an effective surge attenuating power cable, therefore, is to determine the optimum conductance for each semiconductive layer of the cable insulation so as to maximize the high frequency power loss per unit length of cable. Referring to Figure 3, the power loss per unit length at a given frequency $w/2\pi$ P is given by

$$P = G_1|V_1|^2 + G_2|V_2|^2$$

V_1 and V_2 being the voltage drops across the inner semiconductive layer and the outer semiconductive layer, respectively, when the applied voltage is one volt,

where

$$V_1 = Z_1/(Z_1 + Z_2 + Z_3 + Z)$$

and

$$V_2 = Z_2/(Z_1 + Z_2 + Z_3 + Z)$$

The impedances Z_1, Z_2 and Z_3 are determined by the electrical characteristics of the semiconductive layers, namely their respective capacitances, per unit length C_1, C_2 and their respective conductances, per unit length G_1, G_2. Thus

$$Z_1 = \frac{1}{G_1} \cdot \frac{1-jwC_1}{1+(wC_1/G_1)^2}$$

$$Z_2 = \frac{1}{G_2} \cdot \frac{1-jwC_2}{1+(wC_2/G_2)^2}$$

Z_3 = -j/w.C

The impedance Z at the frequency $w/2\pi$ is determined by the geometry and conductivities of the inner and outer conductors.

Thus

$$Z = \{\sqrt{w\mu_o}\left(\frac{1}{2\pi a_1\sqrt{2\sigma_1}} + \frac{1}{2\pi a_2\sqrt{2\sigma_3}}\right)(1+j)\} + \frac{jw\mu_o \ln(a_2/a_1)}{2\pi}$$

where
μ_0 = $400\pi \times 10^{-9}$
a_1 = radius of inner conductor
a_2 = inner radius of outer conductor
σ_1 = conductivity of inner conductor
σ_3 = conductivity of outer conductor.

Since all the above parameters are given, or can be measured, one can readily ascertain the conductances G_1,G_2 required in order to maximize the power loss P at the selected frequency. The required condition is given by

$$\frac{\partial P}{\partial G_1} = 0 \quad \text{and} \quad \frac{\partial P}{\partial G_2} = 0$$

In other words, the power loss P per unit length of cable must be maximized with respect to G_1 and G_2.

It should be noted that the above condition can equally be obtained for the case in which the cable insulation has only one semiconductive layer, since in this case Z_1 (or Z_2 as the case may be) becomes zero.

The inventors have investigated a range of specially formulated semiconductive polyolefins and rubbers, consisting of polymeric material loaded with conductive fillers, which might be used in cable manufacture. The measured conductivity and relative permittivity for each one, over a frequency range 1 MHz-50MHz, is given in Table 2.

TABLE 2

ELECTRICAL PROPERTIES OF POLYOLEFINS LOADED WITH SPECIFIED FILLERS

FILLER MATERIAL	FREQUENCY (MHz)				
	1	2	5	10	50
Conventional σ(mS/m)	0.2	0.4	1.7	3.4	11
ε_r	25	24	19	16	9.6
Branched, i.e. high structure XC72(a) σ(S/m)	0.6	0.7	0.8	1.6	11
ε_r	8800	7800	7500	6300	3700
Carbon Fibre (b) σ(S/m)	0.03	0.03	0.03	0.03	0.05
ε_r	39	36	33	29	19
Spherical N990(c) σ(S/m)	1.1	1.1	1.1	1.1	1.2
(660 g/Kg) ε_r	115	115	110	102	64
Carbospheres(d) σ(S/m)	4.5	4.5	4.5	4.5	4.5
ε_r	12	12	12	12	12

ε_r is the relative dielectric permittivity
σ is the conductivity

(a) - Cabot Co., Vulcan XC-72, Carbon black
(b) - Great Lakes Carbon Co., Fortafil
(c) - J.M. Huber Co., BT-1332, carbon black
(d) - Versar Mfg. Inc.

Table 3 illustrates a comparison between the surge attenuations possible, at three different frequencies, 1MHz, 5MHz and 10 MHz, with a conventional 2kV, 2AWG cable and an optimized cable in accordance with the invention. In this case, the conductive filler of the optimized cable consists of carbospheres.

TABLE 3

COMPARISON OF SURGE ATTENUATION FOR A CONVENTIONAL AND OPTIMIZED 5 kV, 2AWG ($34\ mm^2$) CABLE				
		FREQUENCY (MHz)		
		1	5	10
Conventional	ϵ_r σ(mS/m) α(db/m)	25 0.2 0.006	19 1.7 0.04	16 3.4 0.1
Optimized	ϵ_r σ inner (mS/m) σ outer (mS/m) α(db/m)	12 0.7 0.8 0.02	12 3.6 4 0.10	12 7.2 8 0.29
ϵ_r and σ refer to the relative permittivity and conductivity of the semiconductive layers				

Clearly, since the frequency $w/2\pi$ was selected arbitrarily for the purpose of the previous discussion and the spectrum of a surge will normally cover a range of frequencies, a first consideration in the selection of a suitable semiconductive material is that its conductivity and permittivity should not be highly frequency dependent. Evidently the following conductive fillers, according to the tabulated measurements, are quite unsuitable, all being high structure carbon blacks:

BP 2000 carbon black at 250 g/kg loading
BP 2000 carbon black at 120 g/kg loading
XC-72 carbon black at 360 g/kg loading.

On the other hand, the following fillers, compounded with the polyolefin in the amounts indicated in the Table, are most satisfactory so far as frequency dependence is concerned

Carbon fibres at 30 g/kg
Carbospheres at 250 g/kg
Spherical N990 carbon black at 660 g/kg.

It can readily be deduced that the greatly increased performance of these last materials is due to the fact that the filler particles are not highly structured, but are structured as smooth filaments in the case of the carbon fibres, and as spheres in the case of the last two fillers. This is borne out of the fact that the spherical carbon fillers perform even better than the carbon fibres, and all three are spectacularly different in frequency performance, and in permittivity, from the high structure carbon black fillers. Silver-coated glass beads, which also have a nearly spherical structure, also exhibit excellent frequency-insensitive properties.

It will be observed that the polyolefins loaded with fillers which are not highly structured, in contrast to those which are loaded with high structure carbon black, have acceptably low permittivities, and so the semiconductive layers formed of these materials can be designed with low capacitance per unit length.

In summary, the present invention provides a shielded power cable comprising inner and outer conductors separated by a cable insulation system which provides a displacement current leakage path between the conductors for high frequency currents, wherein the cable insulation system incorporates one or more coaxial semiconductive layers, the material of the semiconductive layer or layers having a conductivity which remains substantially constant over the frequency range 1 MHz to 50 MHz, and a relative permittivity which does not exceed about 12 over the frequency range 0.1 MHz to 50 MHz.

The material of the semiconductive layer or layers is an extrudable polymeric material, or blend of polymeric materials, commonly used in cable manufacture, loaded with a conductive filler. The particles of the filler are essentially smooth surfaced, namely filamentary or spherical, in contrast to the highly structured particles of high structure carbon blacks. The conductive particles may be carbon fibres, carbospheres or carbon black typified by the Spherical N990 manufactured by J.M. Huber Co. Carbon fibres are preferred because of the relatively low loading requirements.

Claims

1. An electrical power transmission system comprising inner and outer coaxial conductors (10,11) separated by an insulation system, the insulation system extending longitudinally with respect to the

conductors and comprising first and second coaxial layers defining a displacement current path between the conductors for high frequency currents, the first layer being a semiconductive layer (12) presenting a conductance G_1 and a capacitance C_1 per unit length, and the second layer being an insulating layer (14) around the first layer and presenting a capacitance C per unit length, characterised in that the conductivity, relative permittivity and the thickness of the first layer are such that the power loss per unit length in the first layer due to displacement current flowing radially through the first and second layers between the inner and outer conductors is maximized with respect to the conductance G_1 per unit length, at least over the frequency range 0.1 MHz - 50 MHz.

2. A system according to claim 1, further comprising a third coaxial layer (13) between the second layer and outer conductor and in the displacement current path between the conductors, the third layer being a semiconductive layer (13) presenting a conductance G_2 and a capacitance C_2 per unit length, characterised further in that the conductivity, relative permittivity, and thickness of the third layer are such that the power loss per unit length in the third layer due to displacement current flowing radially through the first, second and third layers between the inner and outer conductors is maximized with respect to the conductance G_2 per unit length, at least over the frequency range 0.1 MHz - 50 MHz.

3. A system according to claim 2, wherein the first and third semiconductive layers are of the same material.

4. A system according to any preceding claim, wherein the material of the or each semiconductive layer has a conductivity which remains substantially constant and a relative permittivity which does not exceed about 12 over the frequency range 0.1 MHz - 50 MHz.

5. A system according to claim 4, wherein the material of the or each semiconductive layer is an extrudable polymeric material loaded with a low structure particulate conductive filler.

6. A system according to claim 5, wherein the polymeric material is a polyolefin or a blend of rubbers.

7. A system according to claim 6, wherein the conductive filler consists of carbon fibres.

8. A system according to claim 6, wherein the conductive filler consists of carbon spheres.

9. A system according to claim 6, wherein the conductive filler is metallic.

10. A system as claimed in any preceding claim, in the form of a shielded power cable.

Patentansprüche

1. Elektrisches Energieübertragungssystem mit inneren und äußeren koaxialen Leitern (10, 11), die durch ein Isolationssystem voneinander getrennt sind, wobei das Isolationssystem sich in Längsrichtung bezüglich der Leiter erstreckt und erste und zweite koaxiale Schichten aufweist, die für Hochfrequenzströme einen Weg für einen Verschiebungsstrom zwischen den Leitern definieren, wobei die erste Schicht eine Halbleiterschicht (12) ist, die pro Längeneinheit eine Leitfähigkeit G_1 und eine Kapazität C_1 aufweist, und die zweite Schicht eine Isolationschicht (14) um die erste Schicht herum ist und pro Längeneinheit eine Kapazität C aufweist, **dadurch gekennzeichnet**, daß die Leitfähigkeit, die relative Dielektrizitätskonstante und die Dicke der ersten Schicht derart sind, daß der Energieverlust pro Längeneinheit in der ersten Schicht aufgrund des in radialer Richtung durch die ersten und zweiten Schichten zwischen den inneren und äußeren Leitern fließenden Verschiebungsstromes bezüglich der Leitfähigkeit G_1 pro Längeneinheit zumindest im Frequenzbereich 0,1 MHZ - 50 MHZ maximal gemacht wird.

2. System nach Anspruch 1, welches weiterhin eine dritte koaxiale Schicht (13) zwischen der zweiten Schicht und dem äußeren Leiter und in dem Weg für den Verschiebungsstrom zwischen den Leitern aufweist, wobei die dritte Schicht eine Halbleiterschicht (13) ist, welche eine Leitfähigkeit G_2 und eine Kapazität C_2 pro Längeneinheit aufweist, weiterhin dadurch gekennzeichnet, daß die Leitfähigkeit, die relative Dielektrizitätskonstante und die Dicke der dritten Schicht derart sind, daß der Energieverlust pro Längeneinheit in der dritten Schicht aufgrund des in radialer Richtung durch die ersten, zweiten und

dritten Schichten zwischen den inneren und äußeren Leitern fließenden Verschiebungsstromes bezüglich der Leitfähigkeit G_2 pro Längeneinheit zumindest in dem Frequenzbereich von 0,1 MHZ - 50 MHZ maximal gemacht wird.

3. System nach Anspruch 2, wobei die ersten und dritten Halbleiterschichten aus demselben Material bestehen.

4. System nach einem der vorstehenden Ansprüche, wobei das Material der bzw. jeder halbleitenden Schicht im Frequenzbereich von 0,1 MHZ bis 50 MHZ eine Leitfähigkeit hat, die im wesentlichen konstant bleibt und eine relaive Dielektrizitätskonstante hat, die einen Wert von etwa 12 nicht überschreitet.

5. System nach Anspruch 4, wobei das Material der bzw. jeder halbleitenden Schicht ein extrudierbares Polymermaterial ist, welches mit einem leitfähigen Füllmaterial aus wenig strukturierten Teilchen gefüllt ist.

6. System nach Anspruch 5, wobei das Polymermaterial ein Polyolefin oder eine Gummimischung ist.

7. System nach Anspruch 6, wobei das leitfähige Füllmaterial aus Kohlefasern besteht.

8. System nach Anspruch 6, wobei das leitfähige Füllmaterial aus Kohlenstoffkugeln besteht.

9. System nach Anspruch 6, wobei das leitfähige Füllmaterial ein Metall ist.

10. System nach einem der vorstehenden Ansprüche, welches die Form eines abgeschirmten Leistungs- bzw. Energieversorgungskabel hat.

Revendications

1. Système de transport d'énergie électrique comprenant des conducteurs coaxiaux intérieur et extérieur (10, 11) séparés par un système d'isolement, le système d'isolement s'étendant longitudinalement par rapport aux conducteurs et comprenant des première et deuxième couches coaxiales définissant un trajet de courant de déplacement entre les conducteurs pour les courants haute fréquence, la première couche étant une couche semi-conductrice (12) présentant une conductance G_1 et une capacité C_1 par unité de longueur, et la deuxième couche étant une couche isolante (14) autour de la première couche et présentant une capacité C par unité de longueur, caractérisé en ce que la conductivité, la permittivité relative et l'épaisseur de la première couche sont telles que la perte d'énergie par unité de longueur dans la première couche, due au courant de déplacement s'écoulant radialement dans les première et deuxième couches entre les conducteurs intérieur et extérieur, soit maximisée en fonction de la conductance G_1 par unité de longueur, au moins sur la plage de fréquences allant de 0,1 MHz à 50 MHz.

2. Système selon la revendication 1, comprenant en outre une troisième couche coaxiale (13) entre la deuxième couche et le conducteur extérieur et dans le trajet de courant de déplacement entre les conducteurs, la troisième couche étant une couche semi-conductrice (13) présentant une conductance G_2 et une capacitance C_2 par unité de longueur, caractérisé, en outre, en ce que la conductivité, la permittivité relative et l'épaisseur de la première couche sont telles que la perte d'énergie par unité de longueur dans la troisième couche, due au courant de déplacement s'écoulant radialement dans les première, deuxième et troisième couches entre les conducteurs intérieur et extérieur, soit maximisée en fonction de la conductance G_2 par unité de longueur, au moins sur la plage de fréquences allant de 0,1 MHz à 50 MHz.

3. Système selon la revendication 2, dans lequel les première et troisième couches semi-conductrices sont faites de la même matière.

4. Système selon l'une quelconque des revendications précédentes, dans lequel la matière de la couche semi-conductrice, ou de chacune des couches semi-conductrices a une conductivité qui demeure sensiblement constante et une permittivité relative qui n'excède pas environ 12 sur la plage de

fréquences allant de 0,1 MHz à 50 MHz.

5. Système selon la revendication 4, dans lequel la matière de la couche semi-conductrice, ou de chaque couche semi-conductrice est une matière polymère extrudable chargée avec une charge conductrice particulaire faiblement structurée.

6. Système selon la revendication 5, dans lequel la matière polymère est une polyoléfine ou un mélange de caoutchouc.

7. Système selon la revendication 6, dans laquelle la charge conductrice est constituée de fibres de carbone.

8. Système selon la revendication 6, dans laquelle la charge conductrice est constituée de sphères de carbone.

9. Système selon la revendication 6, dans laquelle la charge conductrice est métallique.

10. Système selon l'une quelconque des revendications précédentes, sous la forme d'un câble d'énergie blindé.

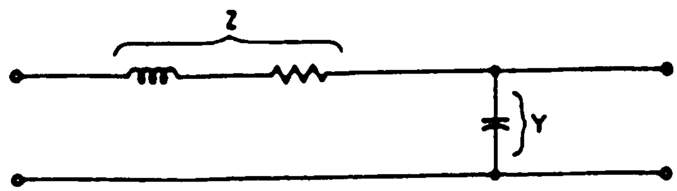

FIG. 1

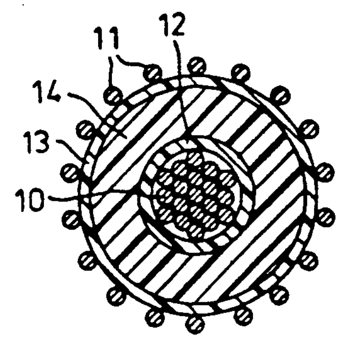

FIG. 2

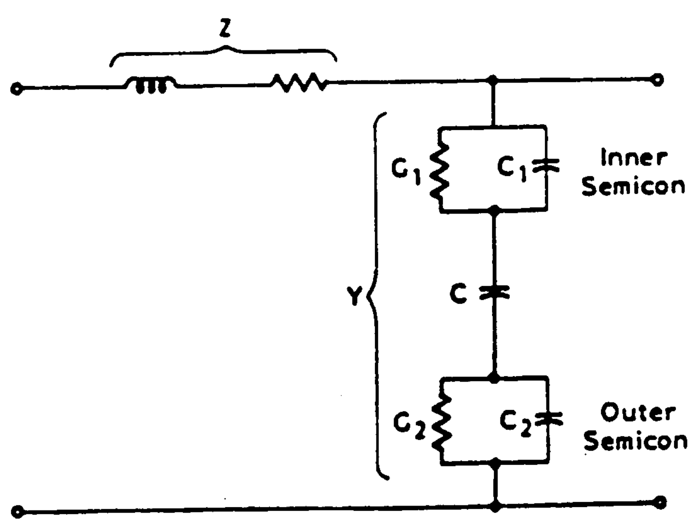

FIG. 3

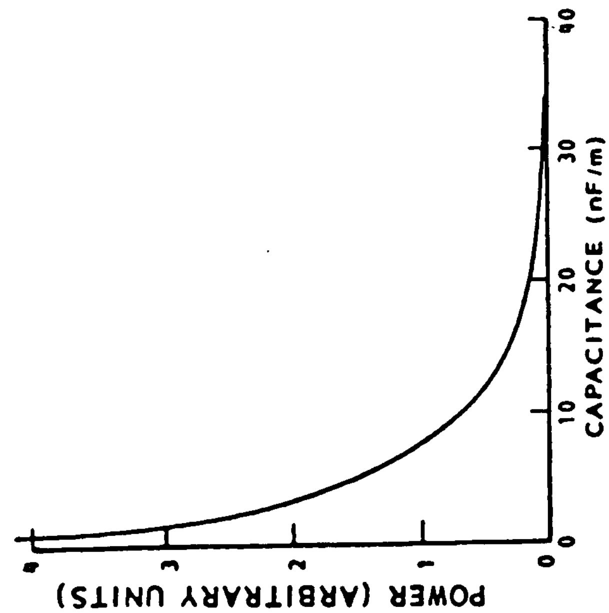
POWER (ARBITRARY UNITS)
0
1
2
3
4
CAPACITANCE (nF/m)
0
10
20
30
40

FIG. 4

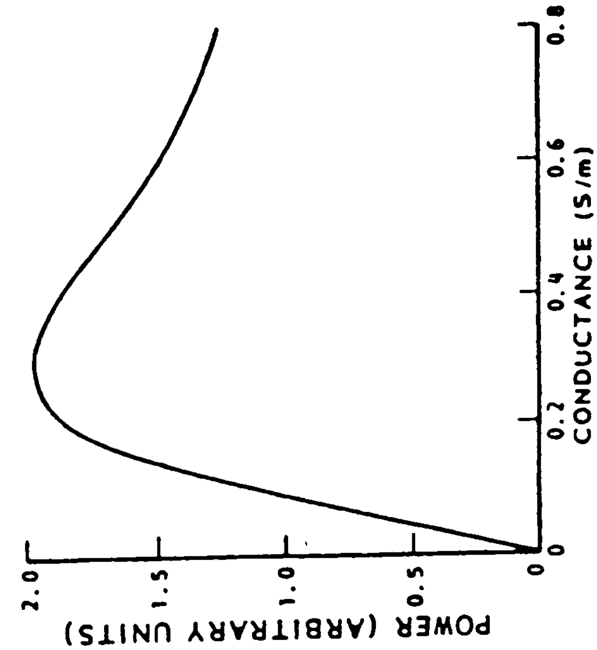
POWER (ARBITRARY UNITS)
0
0.5
1.0
1.5
2.0
CONDUCTANCE (S/m)
0
0.2
0.4
0.6
0.8

FIG. 5

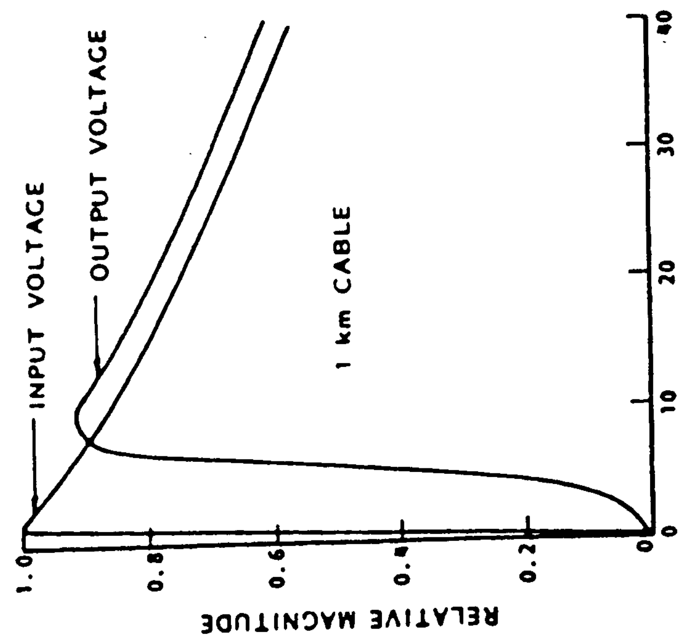
INPUT VOLTAGE
OUTPUT VOLTAGE
1 km CABLE
RELATIVE MAGNITUDE
1.0
0.8
0.6
0.4
0.2
0
10
20
30
40
TIME (μs)

FIG. 6

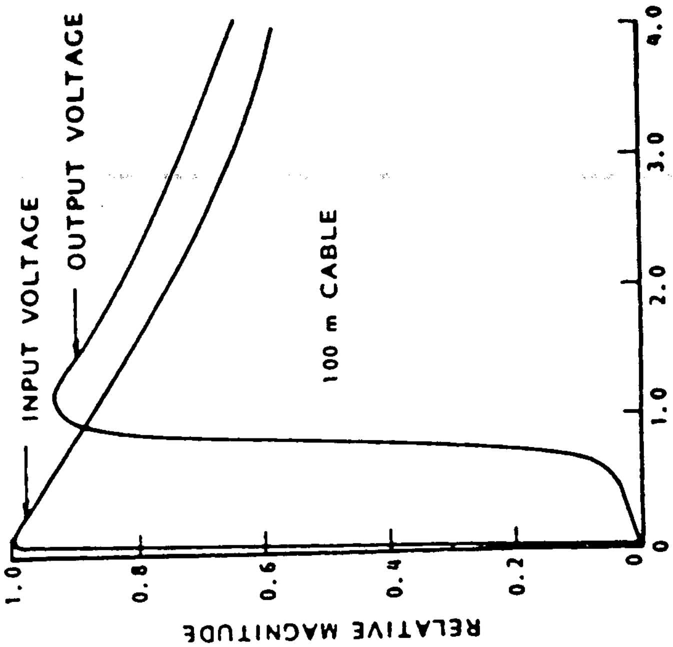
INPUT VOLTAGE
OUTPUT VOLTAGE
100 m CABLE
RELATIVE MAGNITUDE
1.0
0.8
0.6
0.4
0.2
0
1.0
2.0
3.0
4.0
TIME (μs)

FIG. 7